



BYV430W-300P

Dual ultrafast power diode

1 September 2015

Product data sheet

1. General description

2x30A, 300V dual ultrafast power diode in a SOT429 (3-lead TO-247) plastic package.

2. Features and benefits

- Low forward voltage drop
- Fast Switching
- Soft recovery characteristics
- High thermal cycling performance
- Low thermal resistance

3. Applications

- Telecom power supplies
- Welding machines
- Secondary rectification in SMPS

4. Quick reference data

Table 1. Quick reference data

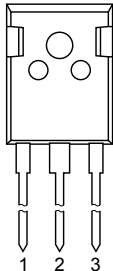
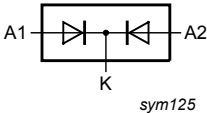
| Symbol | Parameter | Conditions | | Min | Typ | Max | Unit |
|------------------------|-------------------------------------|--|--|-----|------|------|------|
| V _{RRM} | repetitive peak reverse voltage | | | - | - | 300 | V |
| I _{F(AV)} | average forward current | δ = 0.5 ; T _{mb} ≤ 103 °C; square-wave pulse; per diode; Fig. 1 ; Fig. 2 ; Fig. 3 | | - | - | 30 | A |
| I _{O(AV)} | average output current | δ = 0.5 ; T _{mb} ≤ 103 °C; square-wave pulse; both diodes conducting | | - | - | 60 | A |
| I _{FRM} | repetitive peak forward current | δ = 0.5 ; t _p = 25 μs; square-wave pulse; per diode | | - | - | 60 | A |
| I _{FSM} | non-repetitive peak forward current | t _p = 10 ms; T _{j(init)} = 25 °C; sine-wave pulse; per diode; Fig. 4 | | - | - | 300 | A |
| | | t _p = 8.3 ms; T _{j(init)} = 25 °C; sine-wave pulse; per diode; Fig. 4 | | - | - | 330 | A |
| Static characteristics | | | | | | | |
| V _F | forward voltage | I _F = 30 A; T _j = 25 °C; Fig. 6 | | - | 1 | 1.25 | V |
| | | I _F = 30 A; T _j = 150 °C; Fig. 6 | | - | 0.85 | 1 | V |



| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--------------------------------|-----------------------|--|-----|-----|-----|------|
| Dynamic characteristics | | | | | | |
| t_{rr} | reverse recovery time | $I_F = 1\text{ A}$; $V_R = 30\text{ V}$; $dI_F/dt = 50\text{ A}/\mu\text{s}$; $T_j = 25\text{ }^\circ\text{C}$; Fig. 7 | - | - | 50 | ns |
| | | $I_F = 30\text{ A}$; $V_R = 200\text{ V}$; $dI_F/dt = 200\text{ A}/\mu\text{s}$; $T_j = 25\text{ }^\circ\text{C}$; Fig. 7 | - | 33 | - | ns |
| | | $I_F = 30\text{ A}$; $V_R = 200\text{ V}$; $dI_F/dt = 200\text{ A}/\mu\text{s}$; $T_j = 125\text{ }^\circ\text{C}$; Fig. 7 | - | 62 | - | ns |

5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|------------------------|--|--|
| 1 | A1 | anode 1 |  <p>TO-247 (SOT429)</p> |  <p>sym125</p> |
| 2 | K | cathode | | |
| 3 | A2 | anode 2 | | |
| mb | K | mounting base; cathode | | |

6. Ordering information

Table 3. Ordering information

| Type number | Package | | |
|--------------|---------|---|---------|
| | Name | Description | Version |
| BYV430W-300P | TO-247 | plastic single-ended through-hole package; heatsink mounted; 1 mounting hole; 3 lead TO-247 | SOT429 |

7. Marking

Table 4. Marking codes

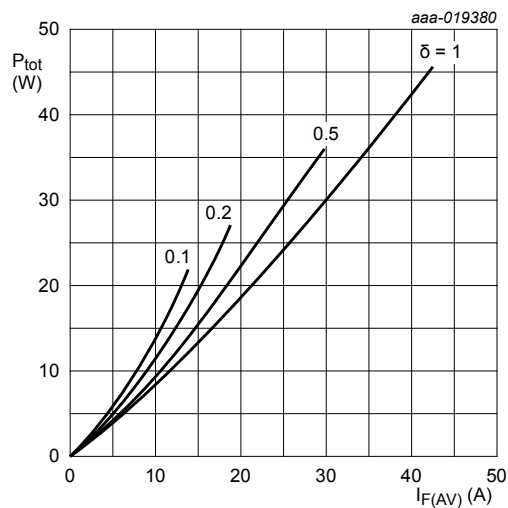
| Type number | Marking code |
|--------------|--------------|
| BYV430W-300P | BYV430W-300P |

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

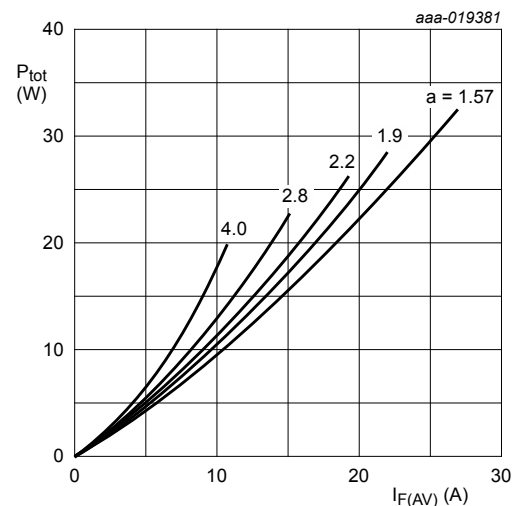
| Symbol | Parameter | Conditions | Min | Max | Unit |
|-------------|-------------------------------------|---|-----|-----|------------------|
| V_{RRM} | repetitive peak reverse voltage | | - | 300 | V |
| V_{RWM} | crest working reverse voltage | | - | 300 | V |
| V_R | reverse voltage | DC | - | 300 | V |
| $I_{F(AV)}$ | average forward current | $\delta = 0.5$; $T_{mb} \leq 103^\circ\text{C}$; square-wave pulse; per diode; Fig. 1 ; Fig. 2 ; Fig. 3 | - | 30 | A |
| $I_{O(AV)}$ | average output current | $\delta = 0.5$; $T_{mb} \leq 103^\circ\text{C}$; square-wave pulse; both diodes conducting | - | 60 | A |
| I_{FRM} | repetitive peak forward current | $\delta = 0.5$; $t_p = 25\text{ }\mu\text{s}$; square-wave pulse; per diode | - | 60 | A |
| I_{FSM} | non-repetitive peak forward current | $t_p = 10\text{ ms}$; $T_{j(\text{init})} = 25^\circ\text{C}$; sine-wave pulse; per diode; Fig. 4 | - | 300 | A |
| | | $t_p = 8.3\text{ ms}$; $T_{j(\text{init})} = 25^\circ\text{C}$; sine-wave pulse; per diode; Fig. 4 | - | 330 | A |
| T_{stg} | storage temperature | | -55 | 175 | $^\circ\text{C}$ |
| T_j | junction temperature | | - | 175 | $^\circ\text{C}$ |



$$I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta}$$

$$V_o = 0.817\text{ V}; R_s = 0.006\text{ }\Omega$$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; per diode; maximum values



$$a = \text{form factor} = I_{F(RMS)} / I_{F(AV)}$$

$$V_o = 0.817\text{ V}; R_s = 0.006\text{ }\Omega$$

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; per diode; maximum values

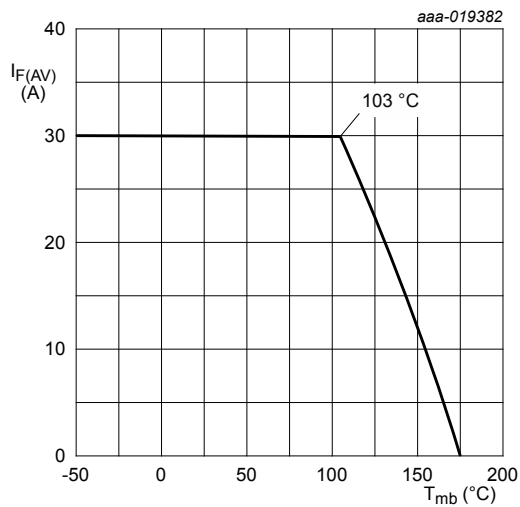


Fig. 3. Average forward current as a function of mounting base temperature; per diode; maximum values

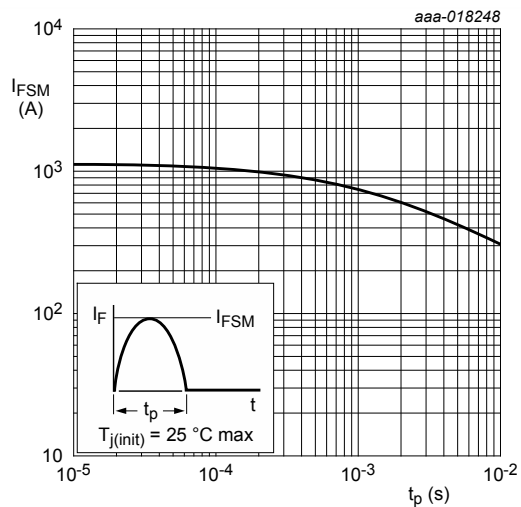
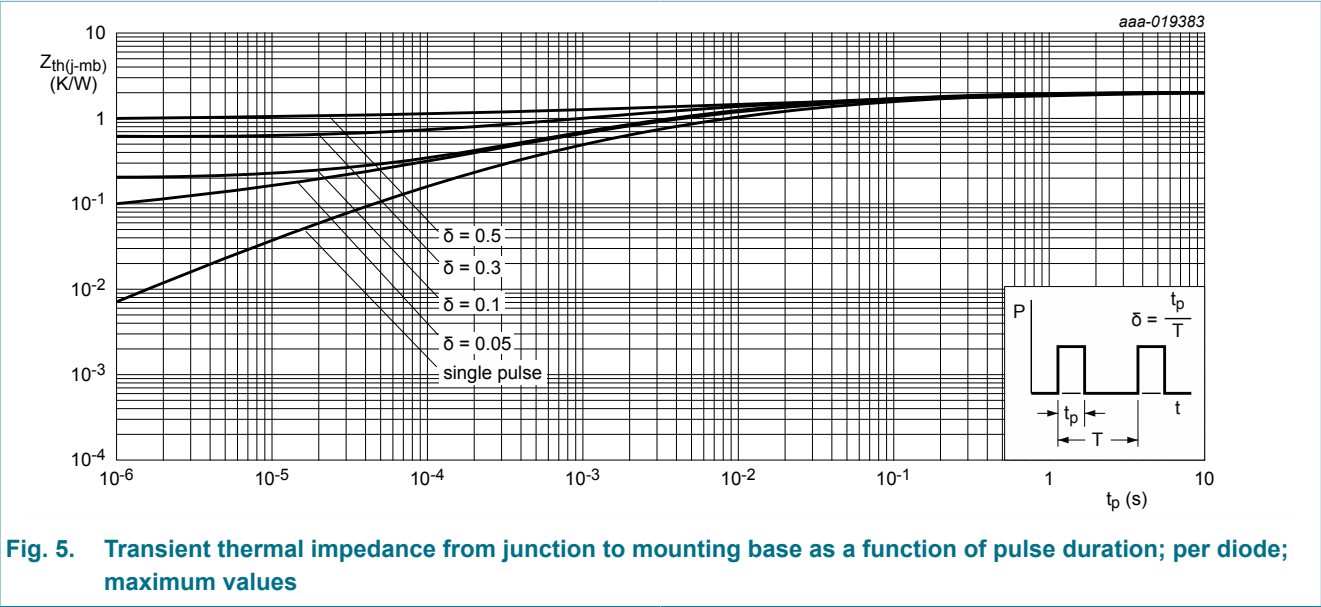


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; per diode; maximum values

9. Thermal characteristics

Table 6. Thermal characteristics

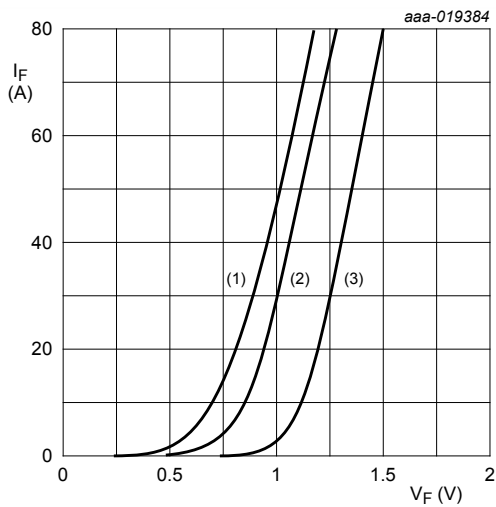
| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|----------------|--|---|-----|-----|-----|------|
| $R_{th(j-mb)}$ | thermal resistance from junction to mounting base | with heatsink compound; per diode; Fig. 5 | - | 0.8 | 2 | K/W |
| | | with heatsink compound; both diodes conducting | - | - | 1.2 | K/W |
| $R_{th(j-a)}$ | thermal resistance from junction to ambient free air | in free air | - | 45 | - | K/W |



10. Characteristics

Table 7. Characteristics

| Symbol | Parameter | Conditions | | Min | Typ | Max | Unit |
|-------------------------|-------------------------------|--|--|-----|------|------|------|
| Static characteristics | | | | | | | |
| V _F | forward voltage | I _F = 30 A; T _j = 25 °C; Fig. 6 | | - | 1 | 1.25 | V |
| | | I _F = 30 A; T _j = 150 °C; Fig. 6 | | - | 0.85 | 1 | V |
| I _R | reverse current | V _R = 300 V; T _j = 25 °C | | - | 0.4 | 10 | μA |
| | | V _R = 300 V; T _j = 150 °C | | - | - | 500 | μA |
| Dynamic characteristics | | | | | | | |
| Q _r | recovered charge | I _F = 30 A; V _R = 200 V; dI _F /dt = 200 A/μs; T _j = 25 °C; Fig. 7 | | - | 89 | - | nC |
| | | I _F = 30 A; V _R = 200 V; dI _F /dt = 200 A/μs; T _j = 125 °C; Fig. 7 | | - | 337 | - | nC |
| t _{rr} | reverse recovery time | I _F = 1 A; V _R = 30 V; dI _F /dt = 50 A/μs; T _j = 25 °C; Fig. 7 | | - | - | 50 | ns |
| | | I _F = 30 A; V _R = 200 V; dI _F /dt = 200 A/μs; T _j = 25 °C; Fig. 7 | | - | 33 | - | ns |
| | | I _F = 30 A; V _R = 200 V; dI _F /dt = 200 A/μs; T _j = 125 °C; Fig. 7 | | - | 62 | - | ns |
| I _{RM} | peak reverse recovery current | I _F = 30 A; V _R = 200 V; dI _F /dt = 200 A/μs; T _j = 25 °C; Fig. 7 | | - | 5.3 | - | A |
| | | I _F = 30 A; V _R = 200 V; dI _F /dt = 200 A/μs; T _j = 125 °C; Fig. 7 | | - | 10.5 | - | A |



$V_o = 0.817\text{ V}; R_s = 0.006\text{ }\Omega$
(1) $T_j = 150\text{ }^\circ\text{C}$; typical values
(2) $T_j = 150\text{ }^\circ\text{C}$; maximum values
(3) $T_j = 25\text{ }^\circ\text{C}$; maximum values

Fig. 6. Forward current as a function of forward voltage, per diode

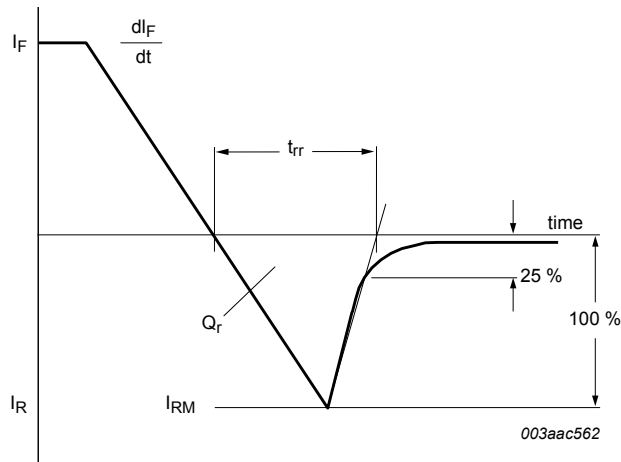


Fig. 7. Reverse recovery definitions; ramp recovery

11. Package outline

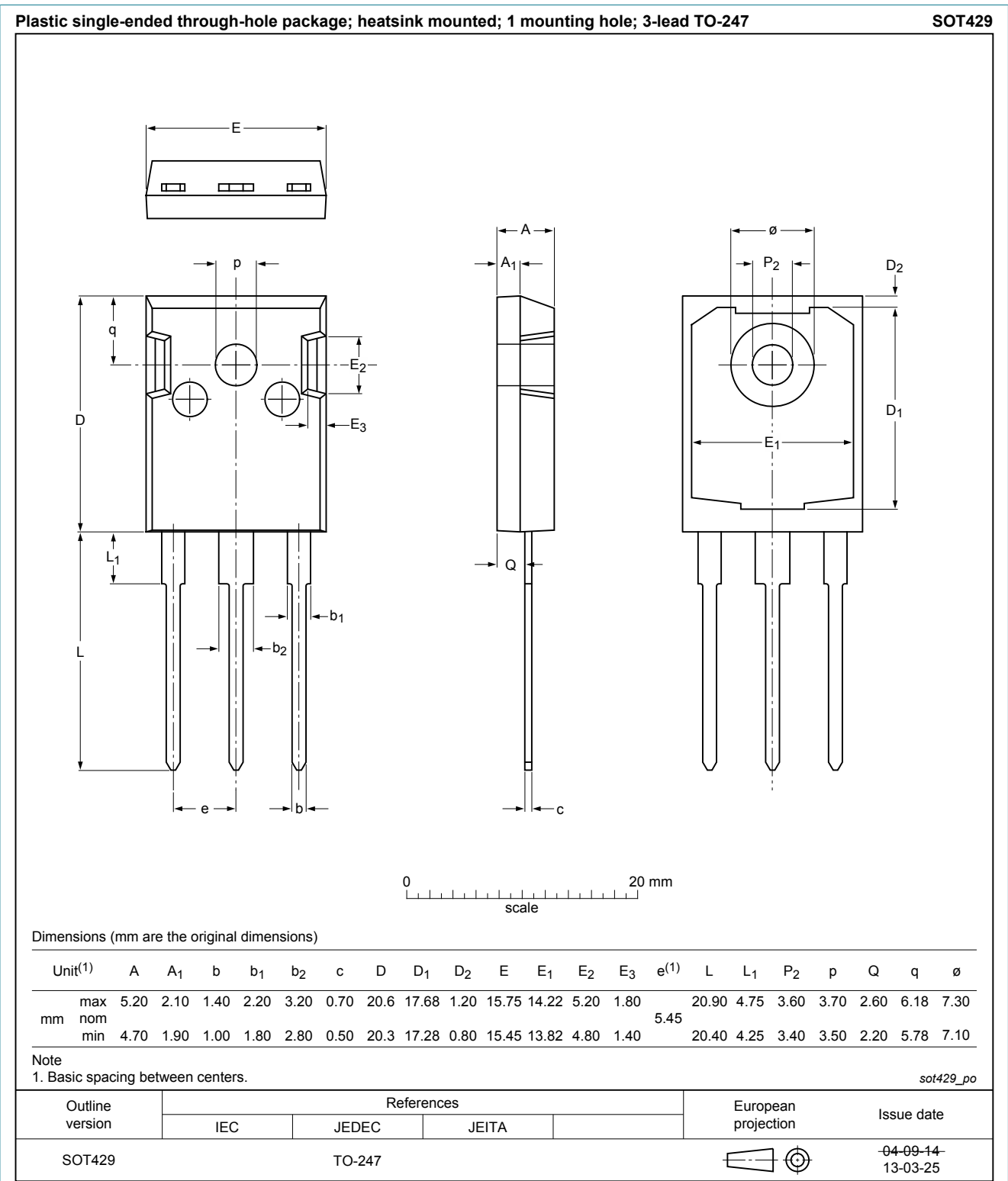


Fig. 8. Package outline TO-247 (SOT429)

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|--------------------------------|--------------------|---|
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